



Diafilm™ TM CVD diamond the ultimate semiconductor thermal management solution

Our customized CVD diamond enables system size reduction, improved reliability and the opportunity to design higher power systems within an existing module footprint

Diamond singulated heat spreaders The optimal thermal solution

Diafilm™ TM is a proven thermal management material ideal for high-power RF, optoelectronic and high-voltage power semiconductor devices. It reduces thermal gradients near a device, making heat sinks more efficient and allows high power devices to be used without increasing the system size or reducing the operating ambient temperature.

Diafilm[™] TM singulated heat spreaders can:

- Lower device temperatures
- Improve reliability
- Expand performance capability

Diafilm[™] TM outperforms other commercially available heat spreader materials, with the highest known thermal conductivity of any solid material at room temperature.

Thermal conductivity



Advantages of Diafilm™ TM microwave CVD diamond heat spreaders

- Highest thermal conductivity of any material •
- Electrically insulating
- Five levels of thermal conductivity available •
- Range of sizes, thicknesses, and metalizations available

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- Broad range of die bonding solutions
- Available in diameters up to 130 mm

| Property | Diafilm TM100 | Diafilm TM130 | Diafilm TM180 | Diafilm TM200 | Diafilm TM220 |
|--|------------------|------------------|------------------|------------------|------------------|
| Thermal conductivity | | | | | |
| @ 300K (W m ⁻¹ K ⁻¹) | >1000 | >1300 | >1800 | >2000 | >2200* |
| @ 425K (W m ⁻¹ K ⁻¹) | >900 | >1200 | >1500 | >1500 | >1620 |
| Thermal expansion coefficient | | | | | |
| @ 300K (ppm K ⁻¹) | 1.10 ± 0.1 | 1.10 ± 0.1 | 1.10 ± 0.1 | 1.10 ± 0.1 | 1.10 ± 0.1 |
| @ 1000K (ppm K ⁻¹) | 4.4 ± 0.1 | 4.4 ± 0.1 | 4.4 ± 0.1 | 4.4 ± 0.1 | 4.4 ± 0.1 |
| Thermal diffusivity | | | | | |
| @ 300K (cm² s⁻¹) | >5.5 | >7.2 | >10.0 | >11.1 | >12.2 |
| Specific heat capacity | | | | | |
| @ 300K (J kg 1 K 1) | 520 | 520 | 520 | 520 | 520 |
| Hardness | | | | | |
| Gpa | 81 ± 18 | 81 ± 18 | 81 ± 18 | 81 ± 18 | 81 ± 18 |
| Fracture toughness | | | | | |
| (MPa m ^{0.5}) | 5.3 - 7.0 | 5.3 - 7.0 | 5.3 - 7.0 | 5.3 - 7.0 | 5.3 - 7.0 |
| Young's modulus | | | | | |
| (GPa) | 1050 | 1050 | 1050 | 1050 | 1050 |
| Poisson's ratio | 0.1 | 0.1 | 0.1 | 0.1 | 0.1 |
| Density | | | | | |
| (10 ³ kg m ⁻³) | 3.52 | 3.52 | 3.52 | 3.52 | 3.52 |

* Measured at 293 K

Going beyond today's technical boundaries

Diafilm™ TM's superior thermal conductivity presents unprecedented reductions in junction temperature, while maintaining the same power level. This offers engineers the opportunity to create more economical and reliable systems.

Modelling and analysing proposed solutions

Our engineers and technologists use the latest computer modelling systems to model and analyse every aspect of the thermal and mechanical properties of a proposed application.

We recommend and provide the optimal size, shape and thickness, and work with customers to most effectively integrate diamond into their applications.

Contact us to find out more Americas

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